

<b>Maximum Ratings</b> $(T_J = 25^{\circ}C \text{ unless otherwise noted})$					
Rating		Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Note 1)	MCR12DCM	V <sub>DRM</sub>	600	V	
(– 40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open)	MCR12DCN	V <sub>RRM</sub>	800	v	
On-State RMS Current (180° Conduction Angles; $T_c = 90$ °C)		I <sub>T (RMS)</sub>	12	А	
Average On–State Current (180° Conduction Angles; $T_c = 90$ °C)		I <sub>T(AV)</sub>	7.8	А	
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_j$ = 125°C)		I <sub>TSM</sub>	100	А	
Circuit Fusing Consideration (t = $8.3 \text{ ms}$ )		l²t	41	A <sup>2</sup> sec	
Forward Peak Gate Power (Pulse Width $\leq$ 10 µsec, T <sub>c</sub> = 90°C)		P <sub>gm</sub>	5.0	W	
Forward Average Gate Power (t = 8.3 msec, $T_c = 90$ °C)		P <sub>GM (AV)</sub>	0.5	W	
Forward Peak Gate Current (Pulse Width $\leq$ 1.0 µsec, T <sub>c</sub> = 90°C)		I <sub>GM</sub>	2.0	А	
Operating Junction Temperature Range		TJ	-40 to 125	°C	
Storage Temperature Range		T <sub>stg</sub>	-40 to 150	°C	

Maximum ratings are those values beyond which component damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, component functional operation is not implied, damage may occur and reliability may be affected. 1. V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics				
Rating	Symbol	Value	Unit	
Thermal Resistance, Junction-to-Case	Re <sub>JC</sub>	2.2		
Thermal Resistance, Junction-to-Ambient	Reja	88	°C/W	
Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>eja</sub>	80		
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C	

# **Electrical Characteristics** - **OFF** ( $T_1 = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current ( $V_{AK}$ = Rated $V_{DRM}$	$T_{J} = 25^{\circ}C$	I <sub>DBM</sub>	-	-	0.01	<u>س</u> ۸
or V <sub>RRM</sub> Gate Open)	T <sub>J</sub> = 125°C	I <sub>RRM</sub>	-	-	5.0	mA

#### Electrical Characteristics - ON (T, = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Мах	Unit
Peak Forward On–State Voltage (Note 2) ( $I_{TM}$ = 16 A)		V <sub>TM</sub>	-	1.3	1.9	V
Gate Trigger Current (Continuous dc)	T <sub>J</sub> = 25°C		2.0	7.0	20	
$(V_{D} = 12 \text{ V}; \text{ R}_{L} = 100 \Omega)$	$T_{J} = -40^{\circ}C$	$T_J = -40^{\circ}C$	-	_	40	mA
Gate Trigger Voltage (Continuous dc)	T <sub>J</sub> = 25°C	V	0.5	0.65	1.0	V
$(V_{\rm D} = 12 \text{ V}, \text{ R}_{\rm L} = 100 \Omega)$	$T_{J} = -40^{\circ}C$	V <sub>gt</sub>	-	_	2.5	v
Gate Non–Trigger Voltage ( $V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega$ )	T <sub>J</sub> = 125°C	V <sub>gd</sub>	0.2	_	_	V
Holding Current	T <sub>J</sub> = 25°C		4.0	22	40	4
$(V_{D} = 12 \text{ V}, \text{ Gate Open, Initiating Current} = 200 \text{ mA})$	$T_{J} = -40^{\circ}C$	Ч <sub>Н</sub>	_	_	80	mA
Latch Current ( $V_p = 12$ V, $I_c = 20 \mu$ A, $T_1 = 25^{\circ}$ C)			4.0	22	40	mA
$(V_{\rm D} = 12 \text{ V}, I_{\rm G} = 20 \mu\text{A}, I_{\rm J} = 25 \text{ C})$ $(V_{\rm D} = 12 \text{ V}, I_{\rm G} = 40 \mu\text{A}, T_{\rm J} = -40^{\circ}\text{C})$		L	_	_	80	



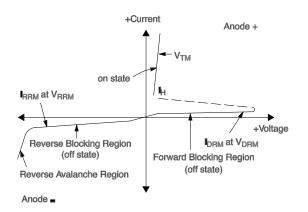
Dynamic Characteristics					
Characteristic	Symbol	Min	Тур	Мах	Unit
Critical Rate of Rise of Off–State Voltage ( $V_{D}$ = Rated $V_{DRM}$ Exponential Waveform, Gate Open, $T_{J}$ = 125°C)	dv/dt	50	200	-	V/µs

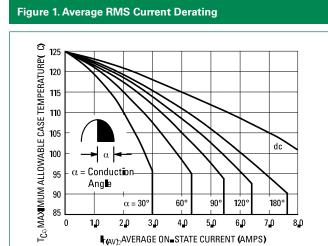
2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

3. 1/8" from case for 10 seconds. 4. Pulse Test: Pulse Width  $\leq$  2.0 msec, Duty Cycle  $\leq$  2%.

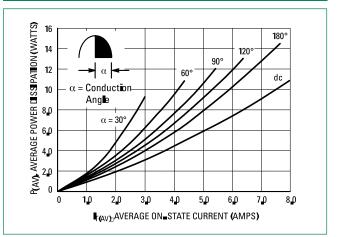
## Voltage Current Characteristic of SCR

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Forward Off State Voltage
I	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Reverse Off State Voltage
I <sub>BRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Maximum On State Voltage
I <sub>H</sub>	Holding Current





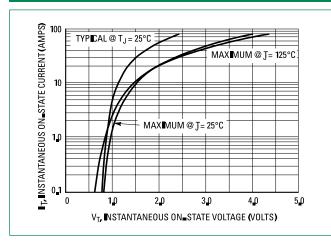
## Figure 2. On-State Power Dissipation



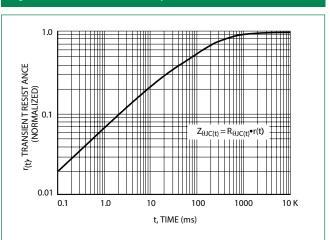
#### © 2019 Littelfuse, Inc. Specifications are subject to change without notice. Revised: 05/10/19



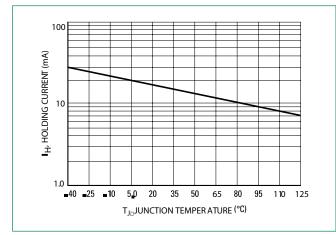
#### Figure 3. On–State Characteristics



#### Figure 4. Transient Thermal Response

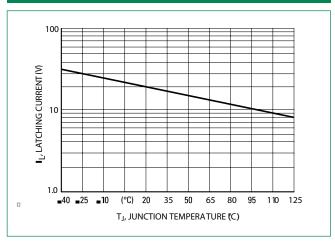


# Figure 5. Typical Gate Trigger Current vs Junction Temperature

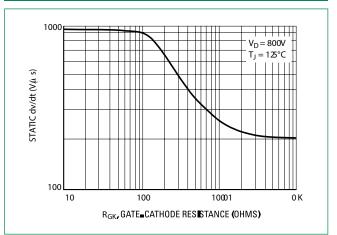


## Figure 7. Typical Holding Current vs Junction Temperature 100 H, HOLDING CURRENT (V) 10 10 **4**0 **2**5 **1**0 50 20 35 50 65 80 95 110 125 T\_ JUNCT DN TEMPERATURE (°C)

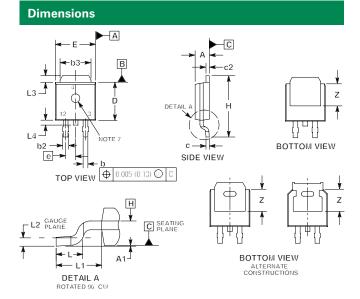
#### Figure 6. Typical Gate Trigger Voltage vs Junction Temperature



#### Figure 9. Exponential Static dv/dt vs Gate–Cathode Resistance





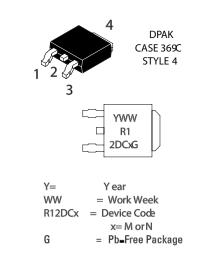


#### Millimeters Inches Dim Min Max Min Max А 0.087 0.094 2.20 2.40 A1 0.000 0.005 0.00 0.12 0.022 0.030 0.55 0.75 b b2 0.026 0.033 0.65 0.85 b3 0.209 0.217 5.30 5.50 0.019 С 0.023 0.49 0.59 c2 0.019 0.023 0.49 0.59 D 0.213 0.224 5.40 5.70 Е 0.252 0.260 6.40 6.60 0.091 2.30 е 0.374 Н 0.406 9.50 10.30 0.058 0.070 1.47 1.78 L L1 0.114 2.90 L2 0.019 0.023 0.49 0.59 L3 0.053 0.065 1.35 1.65 L4 0.028 0.039 0.70 1.00 Ζ 0.154 3.90 -

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

#### Part Marking System



Pin Assignment		
1	Cathode	
2	Anode	
3	Gate	
4	Anode	

Ordering Information				
Device	Package	Shipping		
MCR12DCMT4	DPAK			
MCR12DCMT4G	DPAK (Pb-Free)	2500 /		
MCR12DCNT4	TO-220AB	Tape & Reel		
MCR12DCNT4G	TO-220AB (Pb-Free)			

**Disclaimer Notice** - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littlefuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at: <u>www.littlefuse.com/disclaimer-electronics</u>

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Littelfuse: MCR12DCNT4G MCR12DCMT4G